élantec
HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS

EHA2539/EHA2540

Very High Slew Rate Wideband Operational Amplifier

Features

- High Slew Rate
  EHA2539—600 V/μs
  EHA2540—400 V/μs
- Large open loop gain 15 kV/V (83 dB)
- Wide gain bandwidth
  EHA2539—600 MHz
  EHA2540—400 MHz
- Power bandwidth
  EHA2539—9.5 MHz
  EHA2540—6.3 MHz
- Low offset voltage 0.5 mV
- Low supply current 13 mA
- Output voltage swing ±10V
- MIL-STD-883 Rev. C compliant
- Exact replacements for HA2539 and HA2540

Applications

- Pulse and video amplifiers
- Wideband amplifiers
- High speed sample-hold circuits
- Local area networks

Ordering Information

Part No.	Temp. Range	Pkg.	Outline #
EHA1-2539-2	−55°C to +125°C	14-Pin CerDIP	MDP0014
EHA1-2539-5	0°C to +75°C	14-Pin CerDIP	MDP0014
EHA1-2539/883B	−55°C to +125°C	14-Pin CerDIP	MDP0014
EHA3-2539-5	0°C to +75°C	14-Pin P-DIP	MDP0031
EHA4-2539/883B	−55°C to +125°C	20-Pad LCC	MDP0007
EHA1-2540-2	−55°C to +125°C	14-Pin CerDIP	MDP0014
EHA1-2540-5	0°C to +75°C	14-Pin CerDIP	MDP0014
EHA1-2540/883B	−55°C to +125°C	14-Pin CerDIP	MDP0014
EHA3-2540-5	0°C to +75°C	14-Pin P-DIP	MDP0031
EHA4-2540/883B	−55°C to +125°C	20-Pad LCC	MDP0007

5962-87787 is the SMD version of EHA2539.
5962-89648 is the SMD version of EHA2540.

General Description

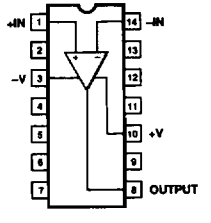
The EHA2539 and EHA2540 monolithic amplifiers are exact replacements for the HA2539 and HA2540 amplifiers. These Elantec amplifiers are well behaved in the presence of capacitive loading, and are stable for closed loop gains of 10 or greater. The EHA2539 is the fastest in the series with a 600 V/μs Slew Rate and 600 MHz gain bandwidth, while the EHA2540 slews at 400 V/μs and has a 400 MHz gain bandwidth. Both amplifiers are fabricated using Elantec's Complementary Bipolar process. For improved guaranteed specifications on offset voltage and supply current see the EL2039/EL2040.

Elantec's high speed amplifiers are widely used in military, video and medical applications. They are especially suited for high speed video amplifiers, pulse detectors, and wide bandwidth filters.

Elantec's EHA2539/883B and EHA2540/883B comply with MIL-STD-883 Revision C in all aspects, including burn-in at 125°C. Elantec's facilities comply with MIL-I-45208A and other applicable quality specifications. For information on Elantec's military processing, see the Elantec document, QRA-2: *Elantec's Military Processing—Monolithic Products.*

Connection Diagrams

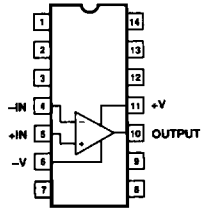
EHA1-2539 EHA3-2539



2539-1

Top View

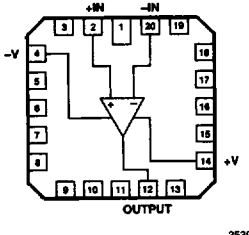
EHA1-2540 EHA3-2540



2539-2

Top View

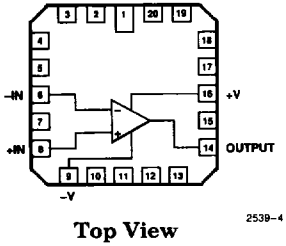
EHA4-2539



2539-3

Top View

EHA4-2540



2539-4

Top View

Note: Non-designated pins are no connects and are not electrically connected internally.

Manufactured under U.S. Patent No. 4,837,523

EHA2539/EHA2540

Very High Slew Rate Wideband Operational Amplifier

Absolute Maximum Ratings (T_A = 25°C)

V_S	Voltage between V+ and V−	35V
V_{DIFF}	Differential Input Voltage	6V
I_{OP}	Output Current, Peak	50 mA
I_{OC}	Output Current, Continuous	25 mA
P_D	Internal Power Dissipation	See Curves
T_A	Operating Temperature Range	
	−2, /883B	−55°C to +125°C
	−5	0°C to +75°C
T_J	Operating Junction Temperature	
	CerDIP, Ceramic LCC	175°C
	Plastic DIP	150°C
T_{ST}	Storage Temperature	−65°C to +150°C
T_{LT}	Lead Temperature	
	(Soldering, 5 seconds)	300°C

Important Note:
All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Level	Test Procedure
I	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at T_A = 25°C and QA sample tested at T_A = 25°C, T_{MAX} and T_{MIN} per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at T_A = 25°C for information purposes only.

DC Electrical Characteristics V_S = ±15V, R_L = 1 kΩ; unless otherwise specified

Parameter	Description	Temp	Min	Typ	Max	−2, /883B Test Level	−5 Test Level	Units
V_{OS}	Offset Voltage (−2, /883B)	25°C		0.5	10	I		mV
		Full			15	I		mV
V_{OS}	Offset Voltage (−5)	25°C		0.5	15		I	mV
		Full			20		III	µV
TCV_{OS}	Average Offset Voltage Drift	Full		20		V	V	µV/°C
I_B	Bias Current	25°C		5	20	I	I	µA
		Full			25	I	III	µA
I_{OS}	Offset Current	25°C		1	6	I	I	µA
		Full			8	I	III	µA
R_{IN}	Input Resistance	25°C		10		V	V	kΩ
C_{IN}	Input Capacitance	25°C		1		V	V	pF
V_{CM}	Common Mode Range	Full	±10	±12		I	II	V
e_{IN}	Input Noise Voltage (f = 1 kHz, R_G = 0Ω)	25°C		6		V	V	nV/√Hz
A_{VOL}	Large Signal Voltage Gain (Note 1)	25°C	10k	15k		I	I	V/V
		Full	5k			I	III	V/V
CMRR	Common-Mode Rejection Ratio (Note 2)	Full	60	90		I	II	dB
V_O	Output Voltage Swing	Full	±10			I	II	V
I_O	Output Current	Full	±10			I	II	mA
R_O	Output Resistance	25°C		30		V	V	Ω
I_S	Supply Current	Full		13	25	I	II	mA
PSRR	Power Supply Rejection Ratio (Note 7)	Full	60	85		I	II	dB

EHA2539/EHA2540

Very High Slew Rate Wideband Operational Amplifier

AC Electrical Characteristics—EHA2539

Parameter	Description	Temp	Min	Typ	Max	−2, /883B Test Level	−5 Test Level	Units
GBW	Gain-Bandwidth Product (Notes 3, 4)	25°C		600		V	V	MHz
FPBW	Full Power Bandwidth (Notes 1, 5, 8)	25°C	8.7	9.5		I	I	MHz
t_r	Rise Time (Note 6)	25°C		7		V	V	ns
OS	Overshoot (Note 6)	25°C		35		V	V	%
SR	Slew Rate (Note 6)	25°C	550	600		I	I	V/μs
t_s	Settling Time (Notes 9, 10) 10V Step to 0.1%	25°C		100		V	V	ns

AC Electrical Characteristics—EHA2540

Parameter	Description	Temp	Min	Typ	Max	−2, /883B Test Level	−5 Test Level	Units
GBW	Gain-Bandwidth Product (Notes 3, 4)	25°C		400		V	V	MHz
FPBW	Full Power Bandwidth (Notes 1, 5, 8)	25°C	5.5	6		I	I	MHz
t_r	Rise Time (Note 6)	25°C		14		V	V	ns
OS	Overshoot (Note 6)	25°C		15		V	V	%
SR	Slew Rate (Note 6)	25°C	350	400		I	I	V/μs
t_s	Settling Time (Notes 9, 10) 10V Step to 0.1%	25°C		70		V	V	ns

Note 1: $V_O = \pm 10V$.

Note 2: Two tests are performed. $V_{CM} = 0V$ to 10V and $V_{CM} = 0V$ to $-10V$.

Note 3: $V_O = 90$ mV.

Note 4: $A_V = 10$.

Note 5: Full Power Bandwidth guaranteed based on slew rate measurement using: $FPBW = \frac{\text{Slew Rate}}{2\pi V_{peak}}$.

Note 6: Refer to Test Circuits section of data sheet.

Note 7: Two tests are performed. V+ = 15V, and V− is changed from −5V to −15V. V− = −15V, and V+ is changed from 5V to 15V.

Note 8: $R_L = 1$ kΩ.

Note 9: Settling time measurements are made with techniques in the following reference: "Take the Guesswork Out of Settling-Time Measurements," EDN, September 19, 1985.

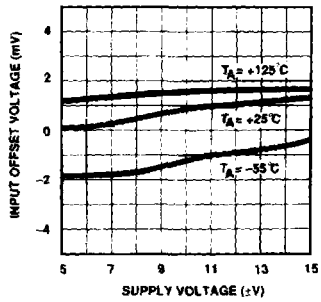
Note 10: $A_V = -10$, $R_L = 1$k.

EHA2539/EHA2540

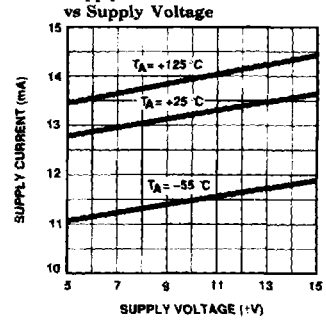
Very High Slew Rate Wideband Operational Amplifier

EHA2539/EHA2540 Typical DC Performance Curves

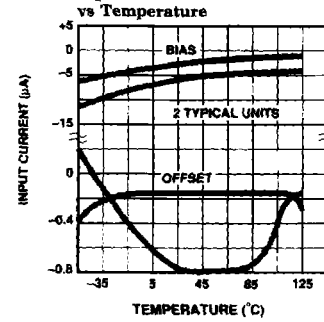
Input Offset Voltage vs Supply Voltage



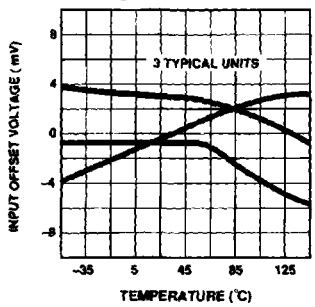
Supply Current vs Supply Voltage



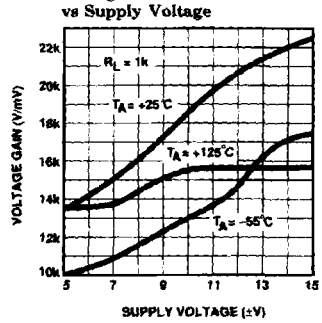
Input Currents vs Temperature



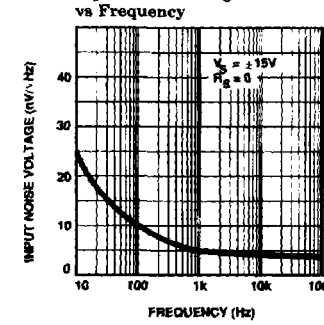
Input Offset Voltage vs Temperature



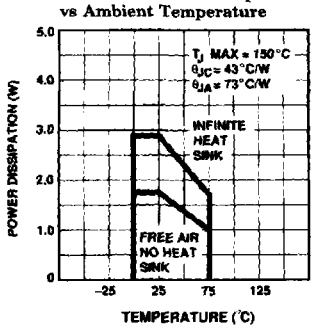
Voltage Gain vs Supply Voltage



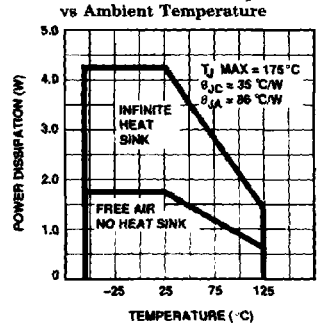
Input Noise Voltage vs Frequency



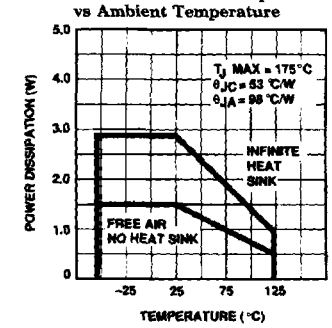
14-Lead Plastic DIP Maximum Power Dissipation vs Ambient Temperature



14-Lead CerDIP Maximum Power Dissipation vs Ambient Temperature



20-Lead LCC Maximum Power Dissipation vs Ambient Temperature



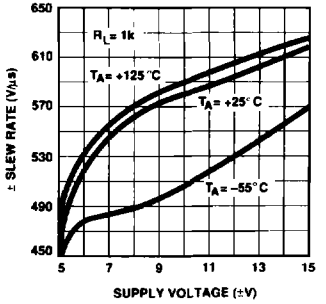
2539-5

EHA2539/EHA2540

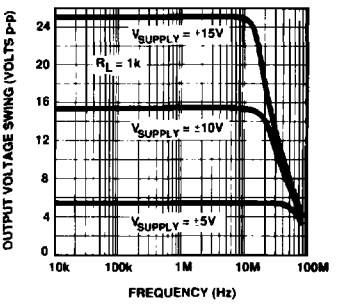
Very High Slew Rate Wideband Operational Amplifier

EHA2539 Typical AC Performance Curves

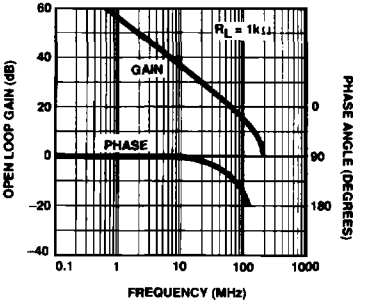
Slew Rate vs Supply Voltage



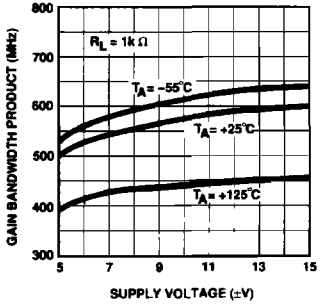
Output Voltage Swing vs Frequency



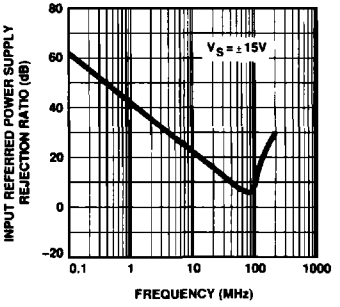
Open Loop Voltage Gain vs Frequency



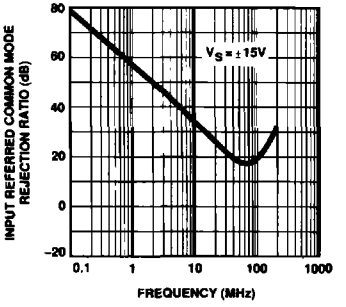
Gain Bandwidth Product at 10 MHz vs Supply Voltage



Input Referred Power Supply Rejection Ratio vs Frequency

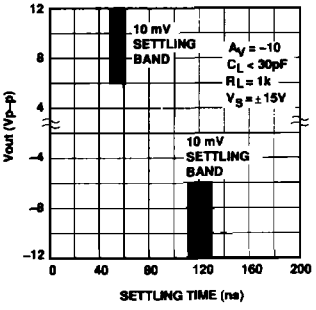


Input Referred Common Mode Rejection Ratio vs Frequency



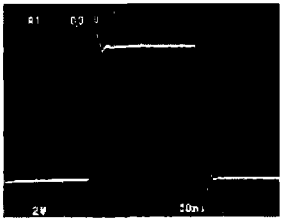
2539-6

Settling Time



2539-7

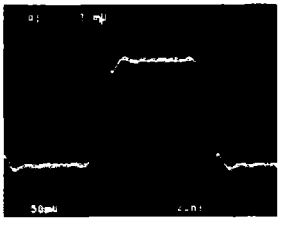
Large Signal Response



V_{IN} = ±0.5V
V_O = ±5V

2539-8

Small Signal Response



V_{IN} = ±10 mV
V_O = ±100 mA

2539-9

EHA2539/EHA2540
Very High Slew Rate Wideband Operational Amplifier

EHA2539 Typical AC Performance Curves — Contd.

HA2539 at Onset of Clipping

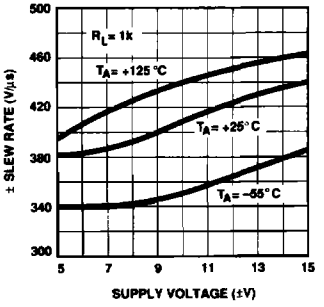
2539-10

EHA2539 at Onset of Clipping

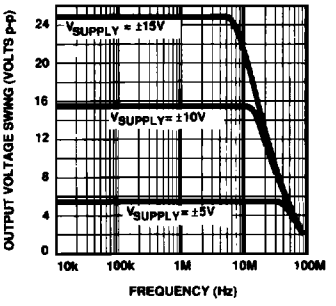
2539-11

EHA2540 Typical AC Performance Curves

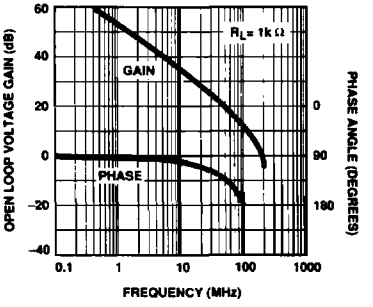
±Slew Rate vs Supply Voltage



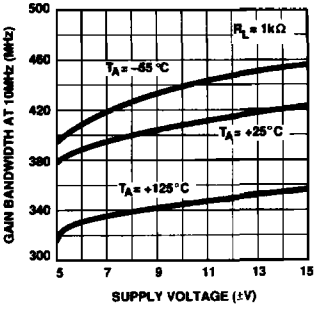
Output Voltage Swing vs Frequency



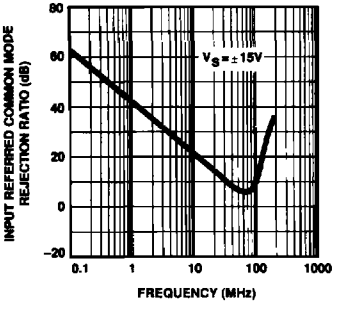
Open Loop Voltage Gain vs Frequency



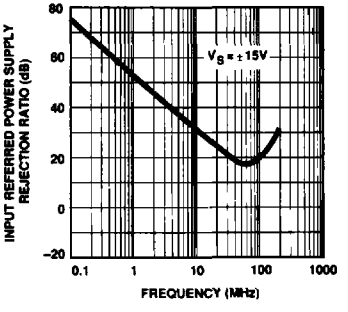
Gain Bandwidth Product at 10 MHz vs Supply Voltage



Input Referred Common Mode Rejection Ratio vs Frequency



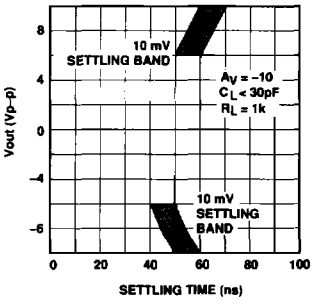
Input Referred Power Supply Rejection Ratio vs Frequency



2539-12

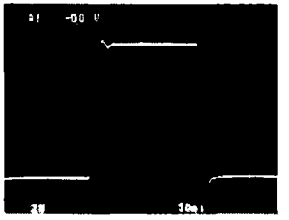
EHA2540 Typical AC Performance Curves — Contd.

Settling Time



2539-13

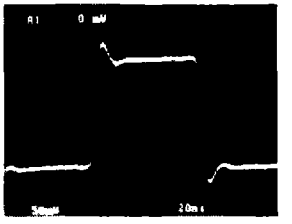
Large Signal Response



V_{IN} = ±0.5V
V_O = ±5V

2539-14

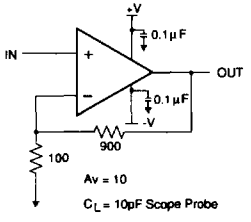
Small Signal Response



V_{IN} = ±10 mV
V_O = ±100 mV

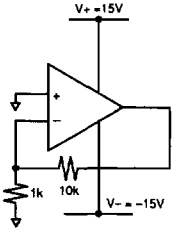
2539-15

Test Circuit



2539-16

Burn-In Circuit

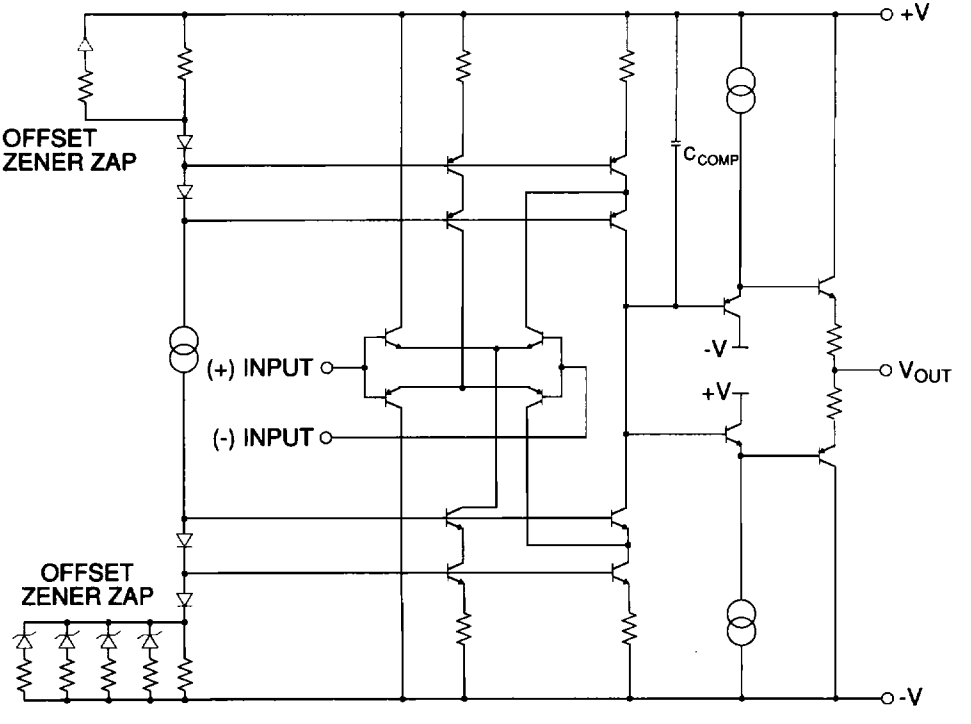


2539-17

EHA2539/EHA2540

Very High Slew Rate Wideband Operational Amplifier

Schematic



2539-16

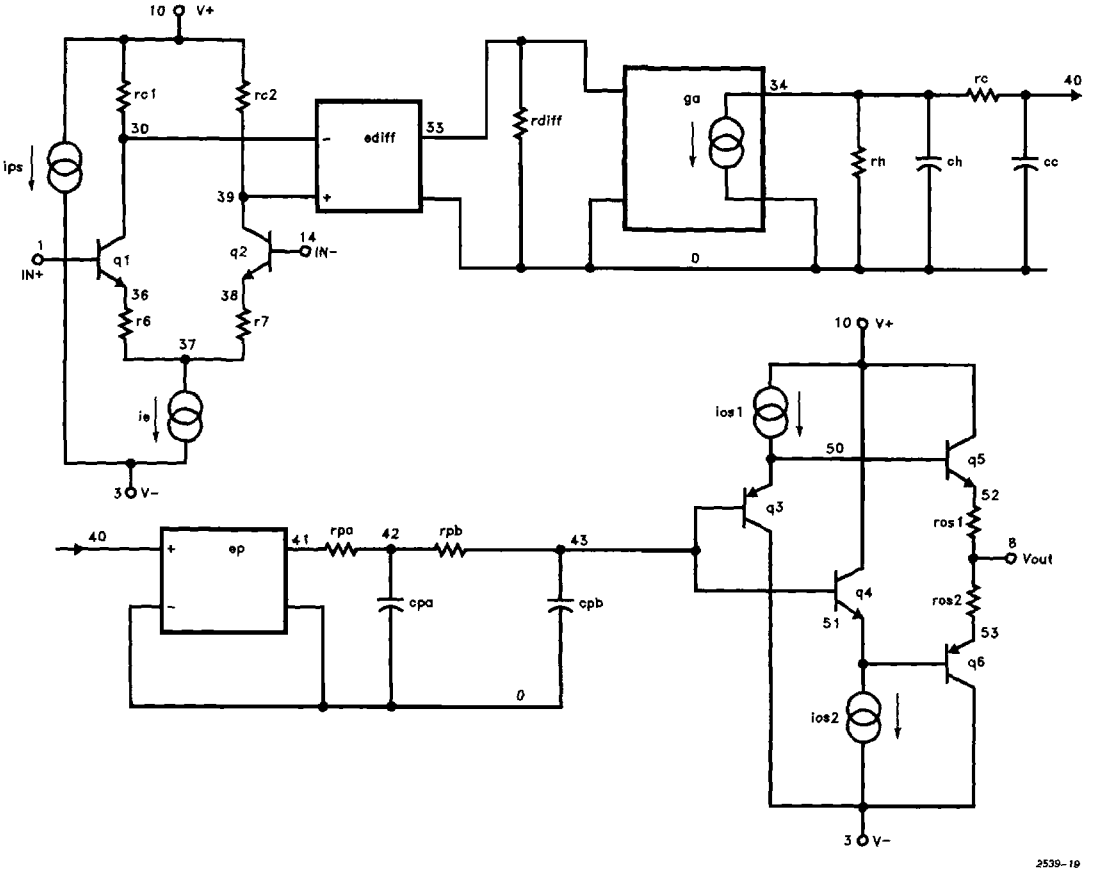
EHA2539 Macromodel

```
* Connections:      +input
*                   |     -input
*                   |     |     +Vsupply
*                   |     |     |     -Vsupply
*                   |     |     |     |     output
*                   |     |     |     |     |
.subckt M2539       1     14    10    3     8
* Input Stage
ie 37 3 1.7mA
r6 36 37 60
r7 38 37 60
rc1 10 30 75
rc2 10 39 75
q1 30 1 36 qn
q2 39 14 38 qna
ediff 33 0 39 30 7.25
rdiff 33 0 1Meg
* Compensation Section
ga 0 34 33 0 5.2m
rh 34 0 .525Meg
ch 34 0 1.5pF
rc 34 40 600
cc 40 0 7pF
* Poles
ep 41 0 40 0 1
rpa 41 42 75
cpa 42 0 7pF
rpb 42 43 50
cpb 43 0 3pF
* Output Stage
ios1 10 50 1.25mA
ios2 51 3 1.25mA
q3 3 43 50 qp
q4 10 43 51 qn
q5 10 50 52 qn
q6 3 51 53 qp
ros1 52 8 25
ros2 8 53 25
* Power Supply Current
ips 10 3 9.5mA
* Models
.model qn npn(is=800.0E-18 bf=170 tf=0.2nS)
.model qna npn(is=864E-18 bf=200 tf=0.2nS)
.model qp pnp(is=800E-18 bf=60 tf=0.2nS)
.ends
```

EHA2539/EHA2540

Very High Slew Rate Wideband Operational Amplifier

EHA2539 Macromodel — Contd.



EHA2540 Macromodel

```
* Connections:      +input
*                   |     -input
*                   |     |     +Vsupply
*                   |     |     |     -Vsupply
*                   |     |     |     |     output
*                   |     |     |     |     |
.subckt M2540       5     4     11    6     10
* Input Stage
ie 37 6 1.3mA
r6 36 37 60
r7 38 37 60
rc1 11 30 75
rc2 11 39 75
q1 30 5 36 qn
q2 39 4 38 qna
ediff 33 0 39 30 7.25
rdiff 33 0 1Meg
* Compensation Section
ga 0 34 33 0 5.2m
rh 34 0 .525Meg
ch 34 0 1.5pF
rc 34 40 600
cc 40 0 7pF
* Poles
ep 41 0 40 0 1
rpa 41 42 75
cpa 42 0 7pF
rpb 42 43 50
cpb 43 0 3pF
* Output Stage
ios1 11 50 1.25mA
ios2 51 6 1.25mA
q3 6 43 50 qp
q4 11 43 51 qn
q5 11 50 52 qn
q6 6 51 53 qp
ros1 52 10 25
ros2 10 53 25
* Power Supply Current
ips 11 6 9.5mA
* Models
.model qn npn(is=800.0E-18 bf=130 tf=0.2nS)
.model qna npn(is=864E-18 bf=150 tf=0.2nS)
.model qp pnp(is=800E-18 bf=60 tf=0.2nS)
.ends
```

EHA2539/EHA2540

Very High Slew Rate Wideband Operational Amplifier

EHA2540 Macromodel — Contd.